

SANYO

No.4319

2SK2010

N-Channel MOS Silicon FET
 Very High-Speed
 Switching Applications

Features

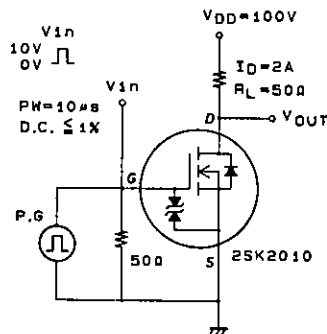
- Low ON resistance.
- Very high-speed switching.
- Low-voltage drive.
- Micaless package facilitating mounting.

Absolute Maximum Ratings at Ta = 25°C

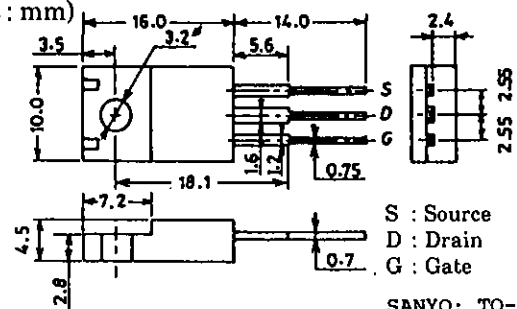
			unit
Drain-to-Source Voltage	V_{DSS}	250	V
Gate-to-Source Voltage	V_{GSS}	± 30	V
Drain Current(DC)	I_D	4	A
Drain Current(Pulse)	I_{DP}	$PW \leq 10\mu s, \text{ duty cycle} \leq 1\%$	16 A
Allowable Power Dissipation	P_D	2.0	W
		$T_c = 25^\circ C$	
Channel Temperature	T_{ch}	150	$^\circ C$
Storage Temperature	T_{stg}	-55 to +150	$^\circ C$

Electrical Characteristics at Ta = 25°C

			min	typ	max	unit
D-S Breakdown Voltage	$V_{(BR)DSS}$	$I_D = 1mA, V_{GS} = 0$	250			V
G-S Breakdown Voltage	$V_{(BR)GSS}$	$I_G = \pm 100\mu A, V_{DS} = 0$	± 30			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 250V, V_{GS} = 0$			100	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS} = \pm 25V, V_{DS} = 0$			± 10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS} = 10V, I_D = 1mA$	1.5		2.5	V
Forward Transfer Admittance	$ Y_{fs} $	$V_{DS} = 10V, I_D = 2A$	2.5	4		S
Static Drain to Source on State Resistance	$R_{DS(on)}$	$I_D = 2A, V_{GS} = 10V$		0.5	0.7	Ω
Input Capacitance	C_{iss}	$V_{DS} = 20V, f = 1MHz$		600		pF
Output Capacitance	C_{oss}	$V_{DS} = 20V, f = 1MHz$		100		pF
Reverse Transfer Capacitance	C_{rss}	$V_{DS} = 20V, f = 1MHz$		40		pF
Turn-ON Delay Time	$t_{d(on)}$	See specified Test Circuit.		12		ns
Rise Time	t_r	"		15		ns
Turn-OFF Delay Time	$t_{d(off)}$	"		65		ns
Fall Time	t_f	"		55		ns
Diode Forward Voltage	V_{SD}	$I_S = 4A, V_{GS} = 0$		1.0	1.5	V

Switching Time Test Circuit**Package Dimensions 2063**

(unit: mm)

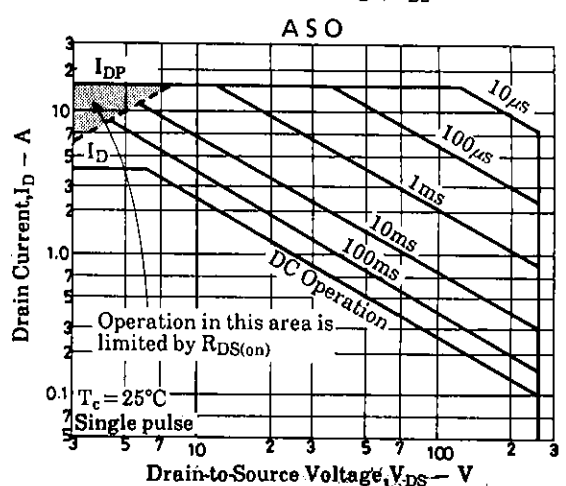
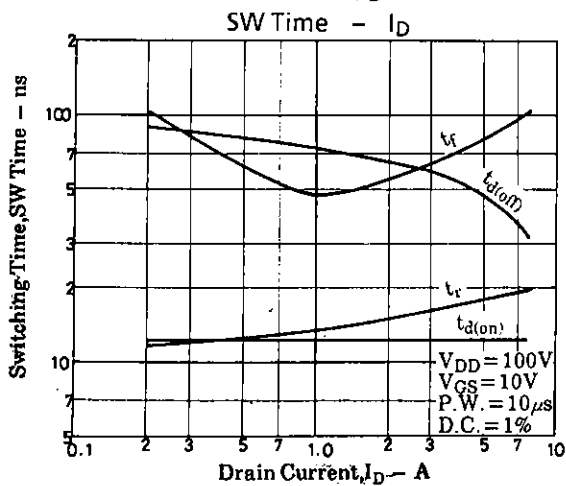
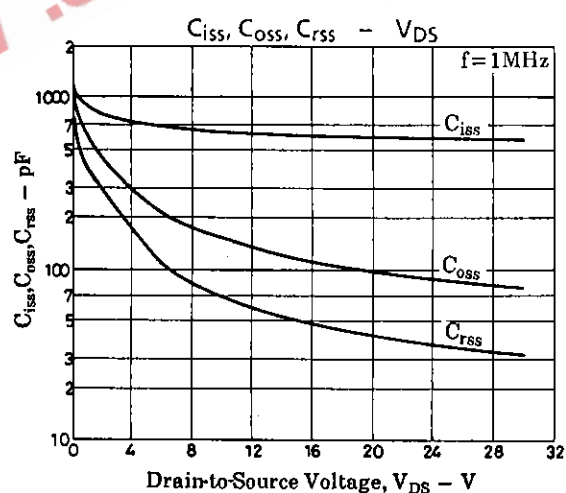
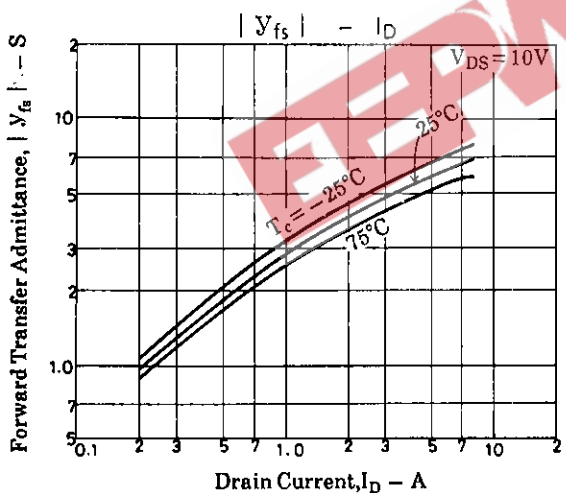
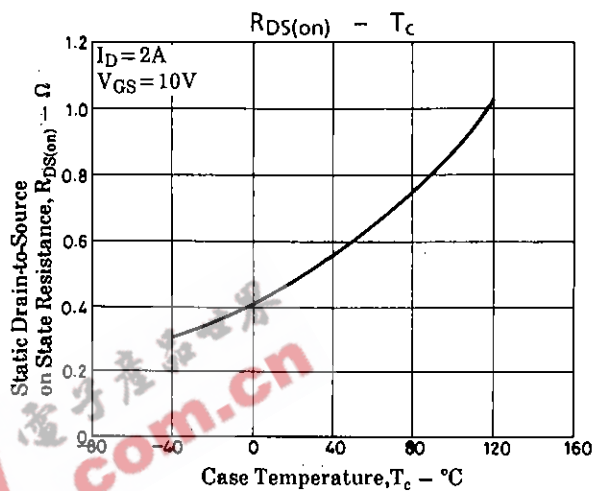
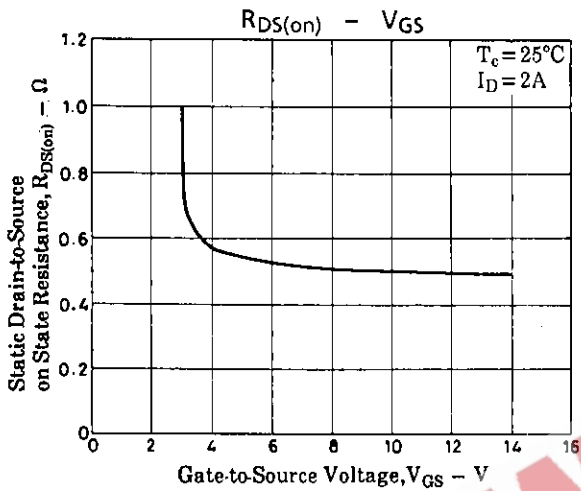
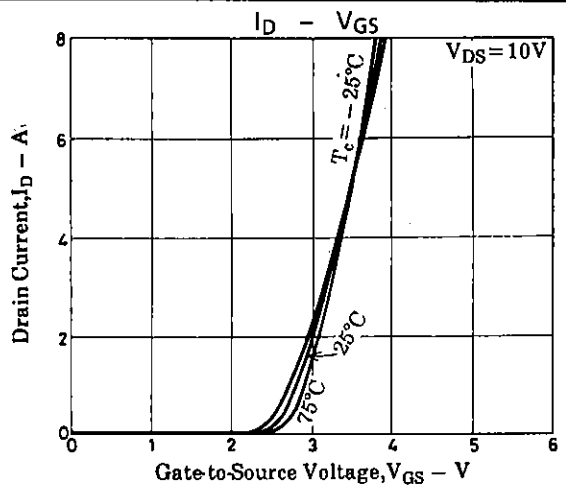
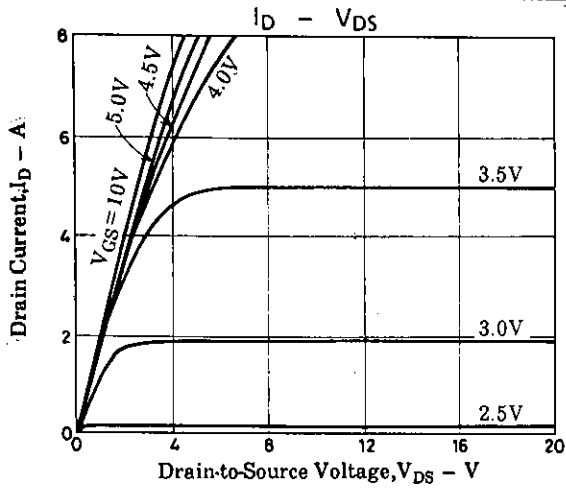


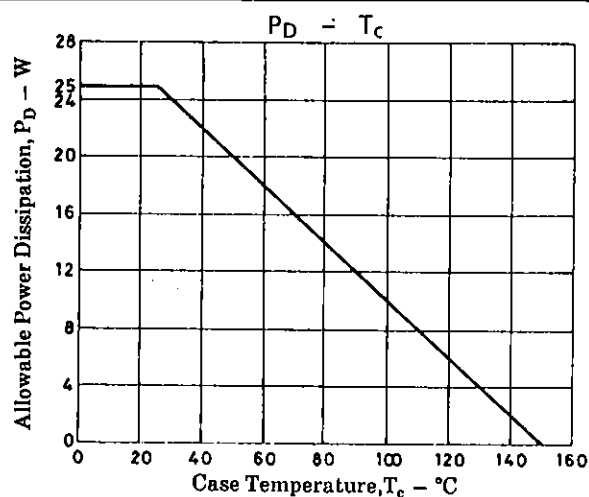
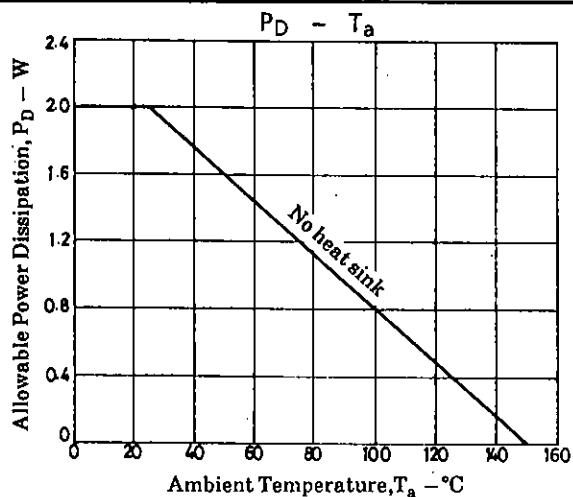
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